Transistors

Switching (250V, 12A) RDN120N25

Features

- 1) Low on-resistance.
- 2) Low input capacitance.
- 3) Exellent resistance to damage from static electricity.

Application

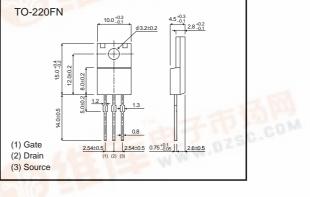
Switching

Structure

Silicon N-channel MOS FET



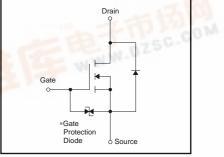
•External dimensions (Unit : mm)



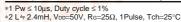
Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit
Drain-Source Voltage		V _{DSS}	250	V
Gate-Source Voltage		V _{GSS}	±30	V
Drain Current	Continuous	ID	12	А
	Pulsed	I _{DP} *1	48	A
Reverse Drain Current	Continuous	ldr	12	А
	Pulsed	I _{DRP} *1	48	A
Avalanche Current		las *2	12	A
Avalanche Energy		E _{AS} *2	216	mJ
Total Power Dissipation (Tc=25°C)		PD	40	W
Channel Temperature		Tch	150	°C
Storage Temperature		T _{stg}	-55 to +150	°C

•Equivalent circuit



*A protection diode is included between the gate and the source terminals to protect the diode against static electricity when the product is in use. Use the protection circuit when the fixed voltages are exceeded.





Transistors

•Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Gate-Source Leakage	lgss	_	_	±10	μA	Vgs=±30V, Vds=0V
Drain-Source Breakdown Voltage	V(BR) DSS	250		_	V	ID=250μA, Vgs=0V
Zero Gate Voltage Drain Current	IDSS	_	_	25	μA	VDS=250V, VGS=0V
Gate Threshold Voltage	VGS (th)	2.0		4.0	V	Vds=10V, Id=1mA
Static Drain-Source On-State Resistance	RDS (on)	_	0.16	0.21	Ω	ID=6A, VGS=10V
Forward Transfer Admittance	Yfs	3.7	6.1	_	S	VDS=10V, ID=6.0A
Input Capacitance	Ciss		1224	_	pF	VDS=10V
Output Capacitance	Coss	_	443	_	pF	Vgs=0V
Reverse Transfer Capacitance	Crss	_	154	_	pF	f=1MHz
Turn-On Delay Time	td (on)	_	17	_	ns	ID=6.0A, VDD≒100V
Rise Time	tr		32	_	ns	Vgs=10V
Turn-Off Delay Time	td (off)	_	58	_	ns	R∟=16.7Ω
Fall Time	tr		28	_	ns	R _G s=10Ω
Reverse Recovery Time	trr	_	169	_	ns	Idr=12A, Vgs=0V
Reverse Recovery Charge	Qrr		0.95	_	μC	di/dt=100A / μs
Total Gate Charge	Qg		31		nC	VDD=125V,VGS=10V,ID=12A

•Electrical characteristic curves

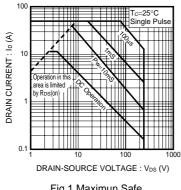


Fig.1 Maximun Safe Operating Area

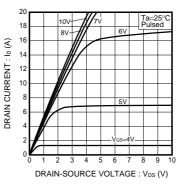


Fig.2 Typical Output Characteristics

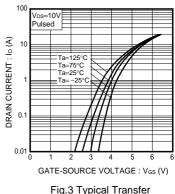
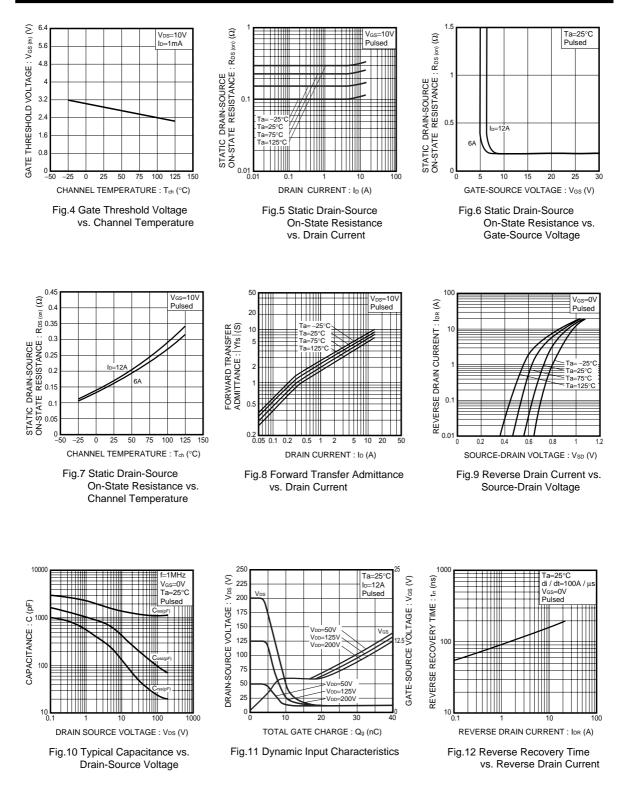
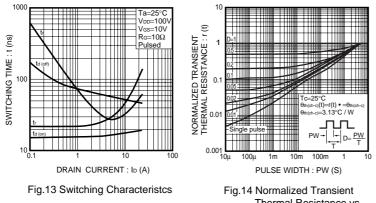


Fig.3 Typical Transfer Characteristics

Transistors



Transistors



Thermal Resistance vs. Pulse Width

Appendix

Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the product described in this document are for reference only. Upon actual use, therefore, please request that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard use and operation. Please pay careful attention to the peripheral conditions when designing circuits and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or otherwise dispose of the same, no express or implied right or license to practice or commercially exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

About Export Control Order in Japan

Products described herein are the objects of controlled goods in Annex 1 (Item 16) of Export Trade Control Order in Japan.

In case of export from Japan, please confirm if it applies to "objective" criteria or an "informed" (by MITI clause) on the basis of "catch all controls for Non-Proliferation of Weapons of Mass Destruction.